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## N-Channel JFETs

### PRODUCT SUMMARY

Part Number	$V_{GS(off)}$ (V)	$V_{(BR)GSS}$ Min (V)	$g_{fs}$ Min (mS)	$I_{DSS}$ Max (mA)
2N4338	-0.3 to -1	-50	0.6	0.6
2N4339	-0.6 to -1.8	-50	0.8	1.5
2N4340	-1 to -3	-50	1.3	3.6
2N4341	-2 to -6	-50	2	9

### FEATURES

- Low Cutoff Voltage: 2N4338 <1 V
- High Input Impedance
- Very Low Noise
- High Gain:  $A_V = 80$  @ 20  $\mu$ A

### BENEFITS

- Full Performance from Low-Voltage Power Supply: Down to 1 V
- Low Signal Loss/System Error
- High System Sensitivity
- High-Quality Low-Level Signal Amplification

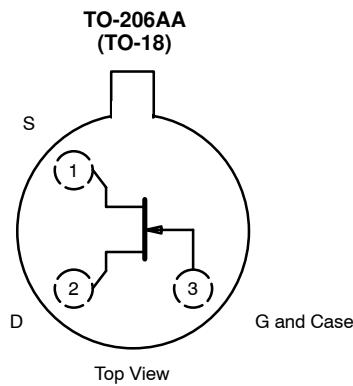
### APPLICATIONS

- High-Gain, Low-Noise Amplifiers
- Low-Current, Low-Voltage Battery-Powered Amplifiers
- Infrared Detector Amplifiers
- Ultrahigh Input Impedance Pre-Amplifiers

### DESCRIPTION

The 2N4338/4339/4340/4341 n-channel JFETs are designed for sensitive amplifier stages at low- to mid-frequencies. Low cut-off voltages accommodate low-level power supplies and low leakage for improved system accuracy.

The TO-206AA (TO-18) package is hermetically sealed and suitable for military processing (see Military Information). For similar products in TO-226AA (TO-92) and TO-236 (SOT-23) packages, see the J/SST201 series data sheet.



### ABSOLUTE MAXIMUM RATINGS

Gate-Source/Gate-Drain Voltage .....	-50 V
Forward Gate Current .....	50 mA
Storage Temperature .....	-65 to 200°C
Operating Junction Temperature .....	-55 to 175°C

Lead Temperature (1/16" from case for 10 sec.) .....	300°C
Power Dissipation <sup>a</sup> .....	300 mW

#### Notes

a. Derate 2 mW/°C above 25°C

For applications information see AN102 and AN106.

**SPECIFICATIONS FOR 2N4338 AND 2N4339 ( $T_A = 25^\circ C$  UNLESS OTHERWISE NOTED)**

Parameter	Symbol	Test Conditions	Typ <sup>a</sup>	Limits				Unit	
				2N4338		2N4339			
				Min	Max	Min	Max		
<b>Static</b>									
Gate-Source Breakdown Voltage	$V_{(BR)GSS}$	$I_G = -1 \mu A, V_{DS} = 0 V$	-57	-50		-50		V	
Gate-Source Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = 15 V, I_D = 0.1 \mu A$		-0.3	-1	-0.6	-1.8		
Saturation Drain Current <sup>b</sup>	$I_{DSS}$	$V_{DS} = 15 V, V_{GS} = 0 V$		0.2	0.6	0.5	1.5	mA	
Gate Reverse Current	$I_{GSS}$	$V_{GS} = -30 V, V_{DS} = 0 V$ $T_A = 150^\circ C$	-2 -4		-100		-100	pA	
Gate Operating Current <sup>b</sup>	$I_G$	$V_{DG} = 15 V, I_D = 0.1 mA$	-2					pA	
Drain Cutoff Current	$I_{D(off)}$	$V_{DS} = 15 V, V_{GS} = -5 V$	2		50		50		
Gate-Source Forward Voltage <sup>c</sup>	$V_{GS(F)}$	$I_G = 1 mA, V_{DS} = 0 V$	0.7					V	
<b>Dynamic</b>									
Common-Source Forward Transconductance	$g_{fs}$	$V_{DS} = 15 V, V_{GS} = 0 V, f = 1 kHz$		0.6	1.8	0.8	2.4	mS	
Common-Source Output Conductance	$g_{os}$				5		15	μS	
Drain-Source On-Resistance	$r_{ds(on)}$	$V_{DS} = 0 V, V_{GS} = 0 V, f = 1 kHz$			2500		1700	Ω	
Common-Source Input Capacitance	$C_{iss}$	$V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz$	5		7		7	pF	
Common-Source Reverse Transfer Capacitance	$C_{rss}$		1.5		3		3		
Equivalent Input Noise Voltage <sup>c</sup>	$\bar{e}_n$	$V_{DS} = 10 V, V_{GS} = 0 V, f = 1 kHz$	6					nV/ √Hz	
Noise Figure	NF	$V_{DS} = 15 V, V_{GS} = 0 V$ $f = 1 kHz, R_G = 1 MΩ$			1		1	dB	

**SPECIFICATIONS FOR 2N4340 AND 2N4341 ( $T_A = 25^\circ C$  UNLESS OTHERWISE NOTED)**

Parameter	Symbol	Test Conditions	Typ <sup>a</sup>	Limits				Unit	
				2N4340		2N4341			
				Min	Max	Min	Max		
<b>Static</b>									
Gate-Source Breakdown Voltage	$V_{(BR)GSS}$	$I_G = -1 \mu A, V_{DS} = 0 V$	-57	-50		-50		V	
Gate-Source Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = 15 V, I_D = 0.1 \mu A$		-1	-3	-2	-6		
Saturation Drain Current <sup>b</sup>	$I_{DSS}$	$V_{DS} = 15 V, V_{GS} = 0 V$		1.2	3.6	3	9	mA	
Gate Reverse Current	$I_{GSS}$	$V_{GS} = -30 V, V_{DS} = 0 V$ $T_A = 150^\circ C$	-2 -4		-100		-100	pA	
Gate Operating Current <sup>b</sup>	$I_G$	$V_{DG} = 15 V, I_D = 0.1 mA$	-2					pA	
Drain Cutoff Current	$I_{D(off)}$	$V_{DS} = 15 V$	$V_{GS} = -5 V$	2		50			
Gate-Source Forward Voltage	$V_{GS(F)}$		$V_{GS} = -10 V$	3			70		
Gate-Source Forward Voltage	$V_{GS(F)}$	$I_G = 1 mA, V_{DS} = 0 V$	0.7					V	

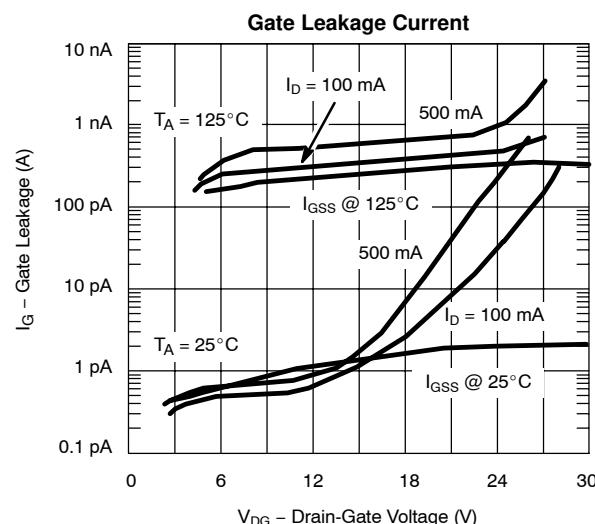
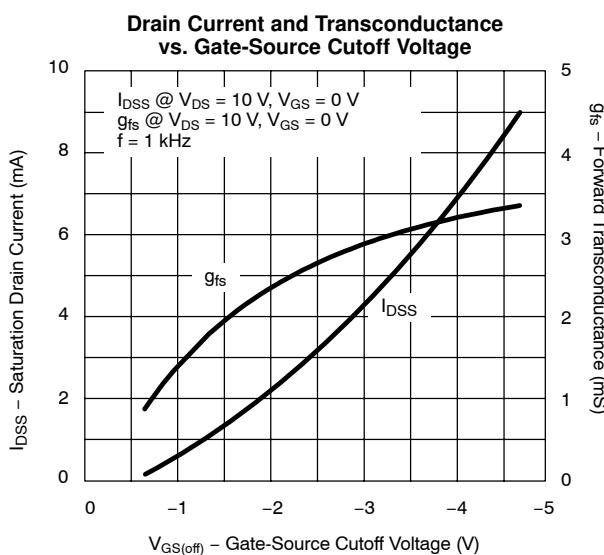
**SPECIFICATIONS FOR 2N4340 AND 2N4341 ( $T_A = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)**

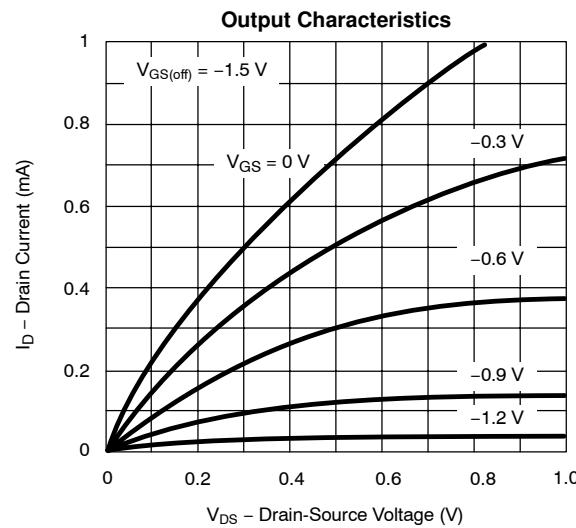
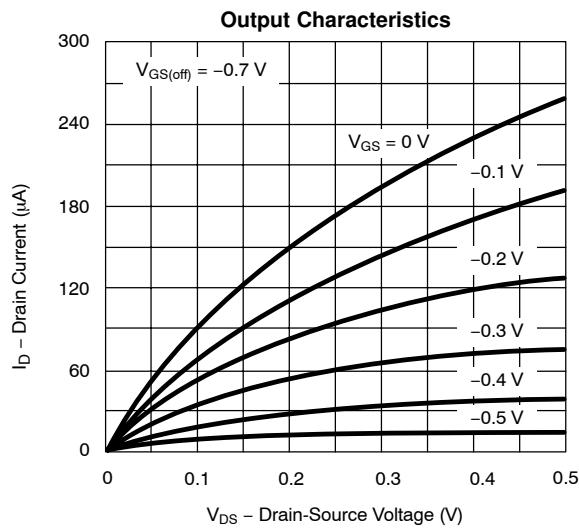
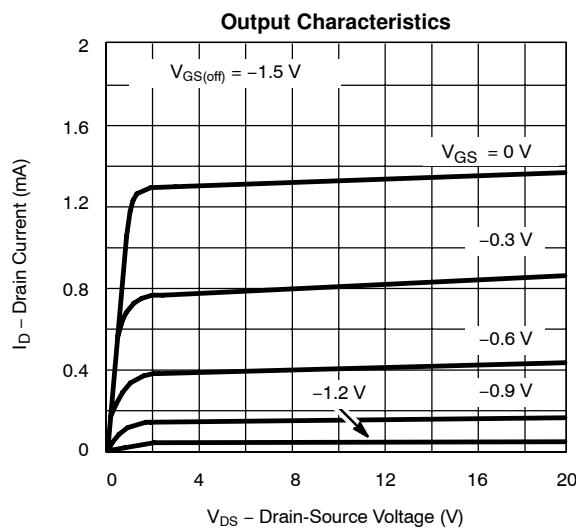
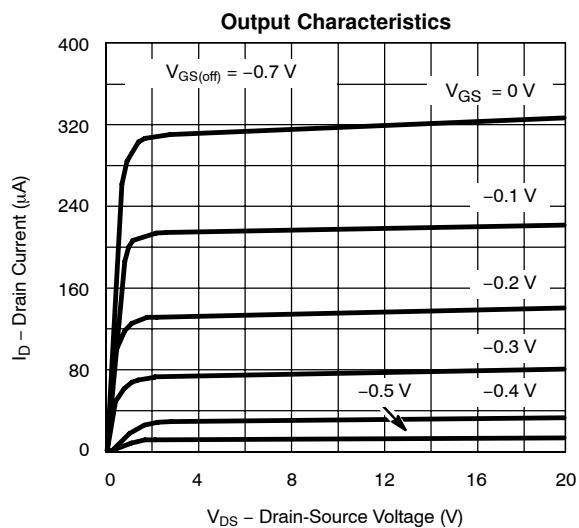
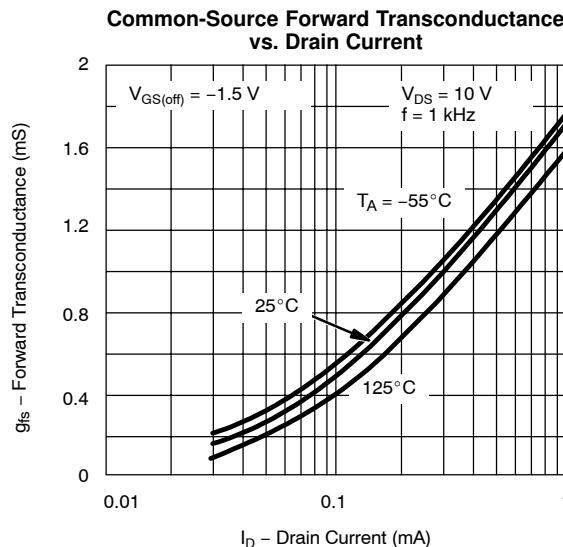
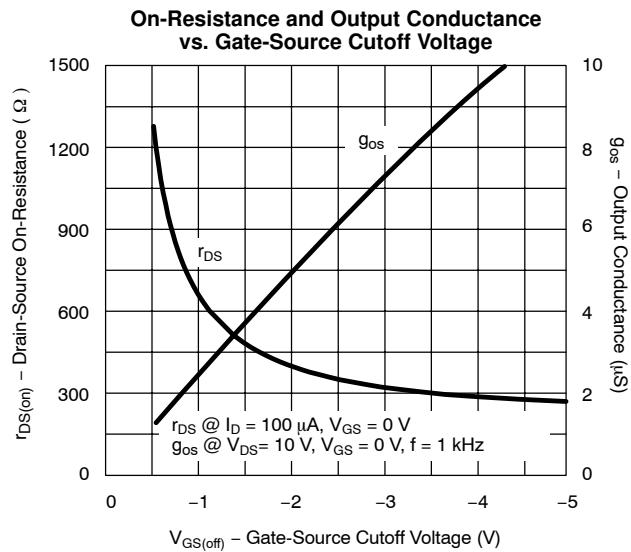
Parameter	Symbol	Test Conditions	Typ <sup>a</sup>	Limits				Unit	
				2N4340		2N4341			
				Min	Max	Min	Max		
<b>Dynamic</b>									
Common-Source Forward Transconductance	$g_{fs}$	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ kHz}$		1.3	3	2	4	mS	
Common-Source Output Conductance	$g_{os}$				30		60	$\mu\text{S}$	
Drain-Source On-Resistance	$r_{ds(on)}$	$V_{DS} = 0 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ kHz}$			1500		800	$\Omega$	
Common-Source Input Capacitance	$C_{iss}$	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	5		7		7	pF	
Common-Source Reverse Transfer Capacitance	$C_{rss}$		1.5		3		3		
Equivalent Input Noise Voltage <sup>c</sup>	$\bar{e}_n$	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ kHz}$	6					$\text{nV}/\sqrt{\text{Hz}}$	
Noise Figure	NF	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}$ $f = 1 \text{ kHz}, R_G = 1 \text{ M}\Omega$			1		1	dB	

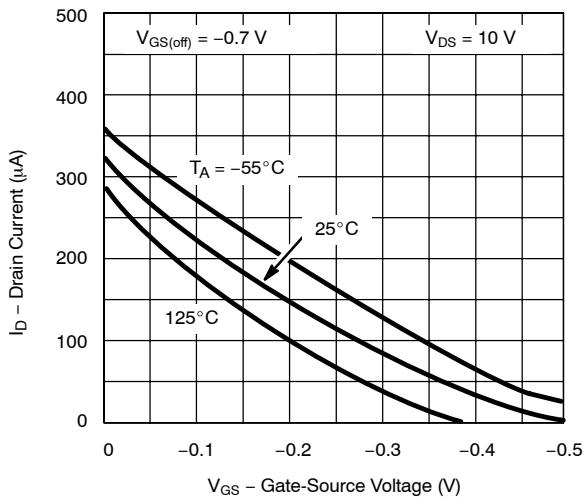
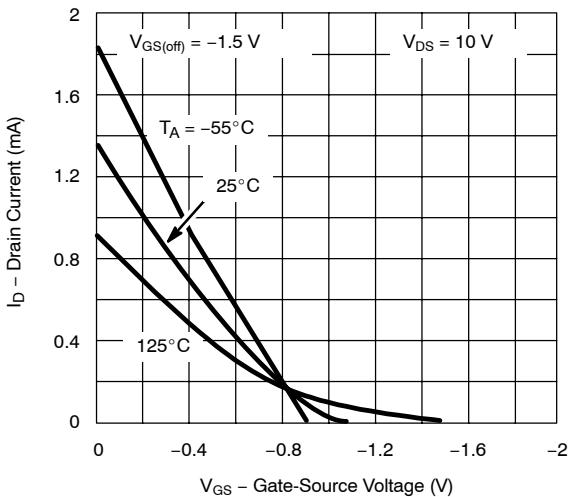
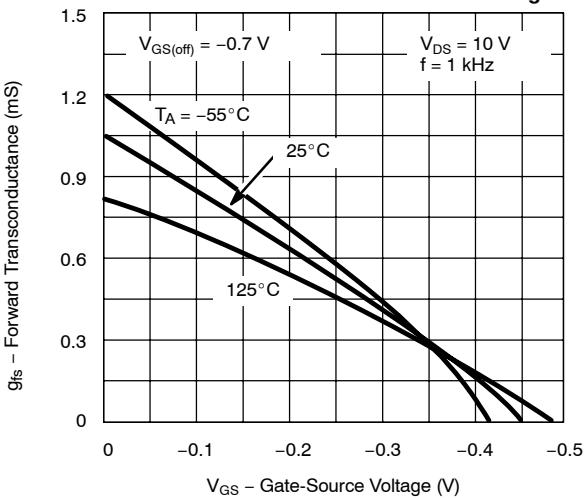
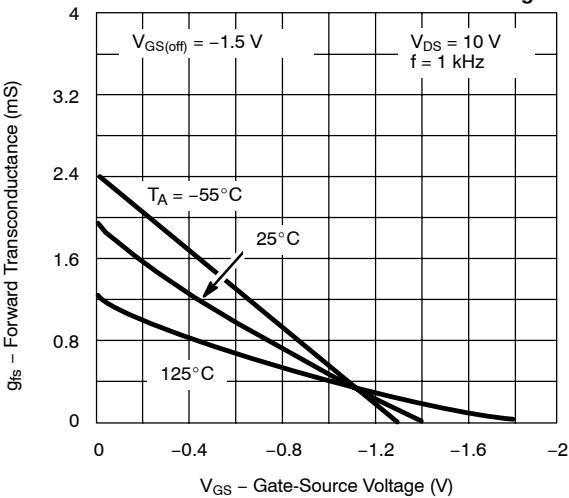
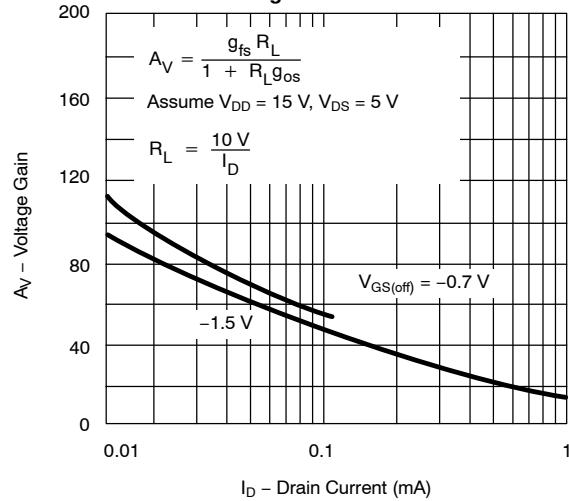
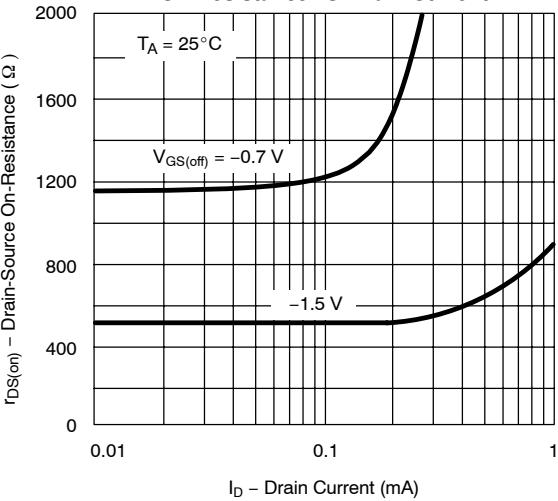
**Notes**

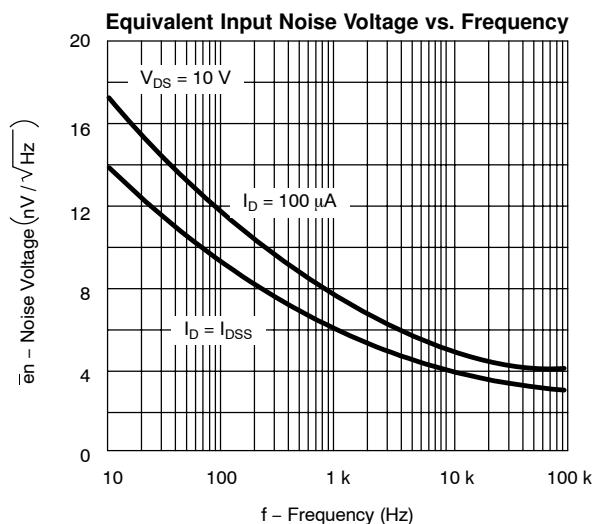
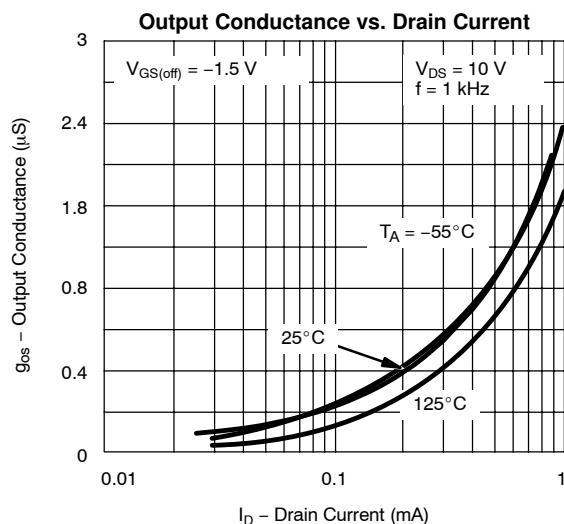
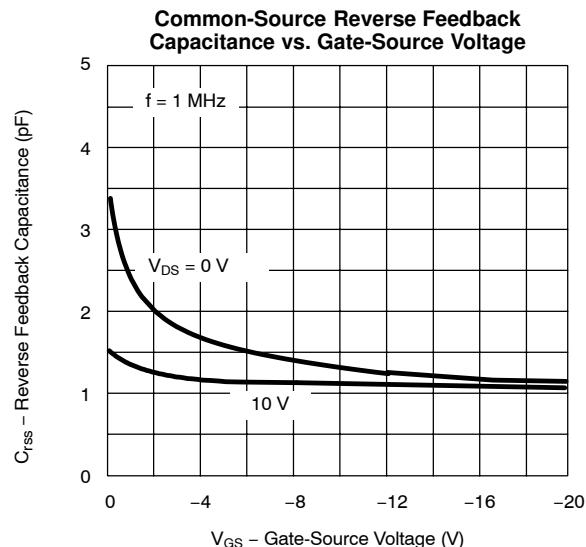
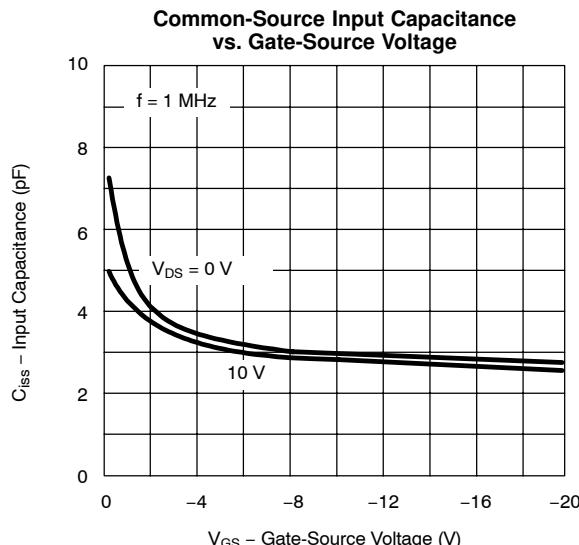
- a. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.  
b. Pulse test: PW  $\leq 300 \mu\text{s}$ , duty cycle  $\leq 3\%$ .  
c. This parameter not registered with JEDEC.

NPA

**TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)**


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**Transfer Characteristics**

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**Transconductance vs. Gate-Source Voltage**

**Transconductance vs. Gate-Source Voltage**

**Circuit Voltage Gain vs. Drain Current**

**On-Resistance vs. Drain Current**


**TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)**



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